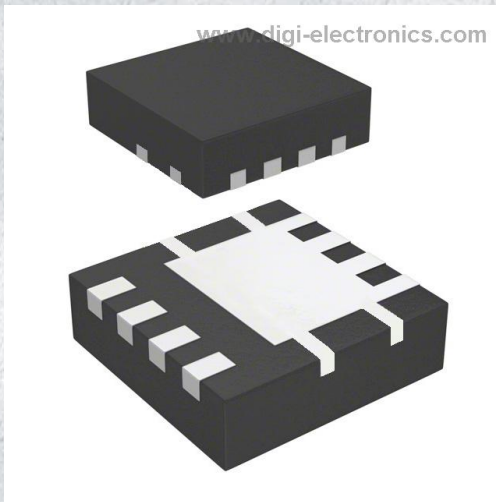


FDMC86240 Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	FDMC86240-DG
Manufacturer	onsemi
Manufacturer Product Number	FDMC86240
Description	MOSFET N-CH 150V 4.6A/16A 8MLP
Detailed Description	N-Channel 150 V 4.6A (Ta), 16A (Tc) 2.3W (Ta), 40W (Tc) Surface Mount 8-MLP (3.3x3.3)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:

FDMC86240

Series:

PowerTrench®

FET Type:

N-Channel

Drain to Source Voltage (Vdss):

150 V

Drive Voltage (Max Rds On, Min Rds On):

6V, 10V

Vgs(th) (Max) @ Id:

4V @ 250µA

Vgs (Max):

±20V

FET Feature:

-

Operating Temperature:

-55°C ~ 150°C (Tj)

Supplier Device Package:

8-MLP (3.3x3.3)

Base Product Number:

FDMC86

Manufacturer:

onsemi

Product Status:

Active

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

4.6A (Ta), 16A (Tc)

Rds On (Max) @ Id, Vgs:

51mOhm @ 4.6A, 10V

Gate Charge (Qg) (Max) @ Vgs:

15 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

905 pF @ 75 V

Power Dissipation (Max):

2.3W (Ta), 40W (Tc)

Mounting Type:

Surface Mount

Package / Case:

8-PowerWDFN

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



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FDMC86240

N-Channel Shielded Gate PowerTrench[®] MOSFET

150 V, 16 A, 51 mΩ

Features

- Shielded Gate MOSFET Technology
- Max $r_{DS(on)}$ = 51 mΩ at $V_{GS} = 10$ V, $I_D = 4.6$ A
- Max $r_{DS(on)}$ = 70 mΩ at $V_{GS} = 6$ V, $I_D = 3.9$ A
- Low Profile - 1 mm max in Power 33
- 100% UIL Tested
- RoHS Compliant

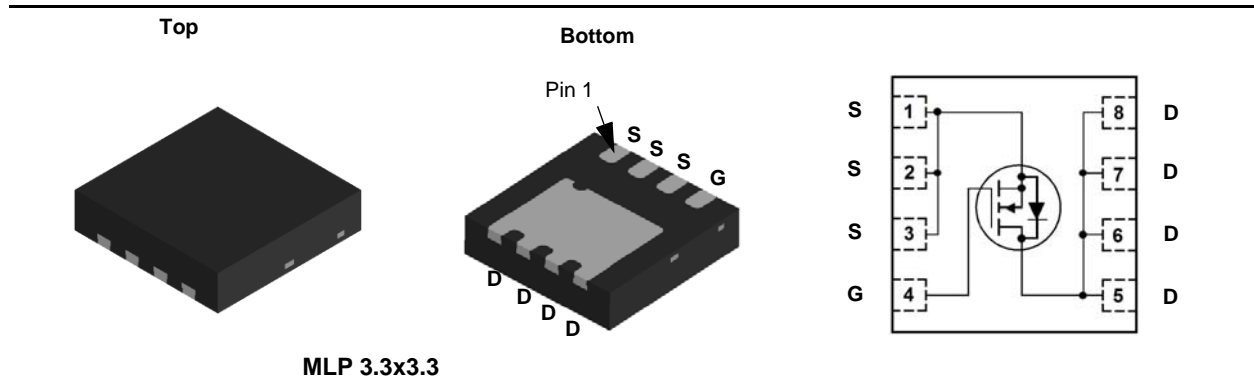


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that incorporates Shielded Gate technology. This process has been optimized for the on-state resistance and yet maintain superior switching performance.

Application

- DC - DC Conversion



MLP 3.3x3.3

MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Rated Value	Units
V_{DS}	Drain to Source Voltage		150	V
V_{GS}	Gate to Source Voltage		±20	V
I_D	Drain Current	-Continuous $T_C = 25$ °C	16	A
		-Continuous $T_A = 25$ °C (Note 1a)	4.6	
		-Pulsed	20	
E_{AS}	Single Pulse Avalanche Energy	(Note 3)	34	mJ
P_D	Power Dissipation	$T_C = 25$ °C	40	W
	Power Dissipation	$T_A = 25$ °C (Note 1a)	2.3	
T_J, T_{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case		3.1	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	53	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC86240	FDMC86240	Power 33	13 "	12 mm	3000 units

FDMC86240 N-Channel Shielded Gate PowerTrench[®] MOSFET

Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
--------	-----------	-----------------	-----	-----	-----	-------

Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250\text{ }\mu\text{A}, V_{GS} = 0\text{ V}$	150			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		101		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 120\text{ V}, V_{GS} = 0\text{ V}$			1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$			± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\text{ }\mu\text{A}$	2.0	2.9	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\text{ }\mu\text{A}$, referenced to $25\text{ }^\circ\text{C}$		-9		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\text{ V}, I_D = 4.6\text{ A}$		44.7	51	m Ω
		$V_{GS} = 6\text{ V}, I_D = 3.9\text{ A}$		51.4	70	
		$V_{GS} = 10\text{ V}, I_D = 4.6\text{ A}, T_J = 125\text{ }^\circ\text{C}$		84.5	97	
g_{FS}	Forward Transconductance	$V_{DS} = 10\text{ V}, I_D = 4.6\text{ A}$		15		S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 75\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		680	905	pF
C_{oss}	Output Capacitance			79	105	pF
C_{rss}	Reverse Transfer Capacitance			4.3	10	pF
R_g	Gate Resistance			0.5		Ω

Switching Characteristics

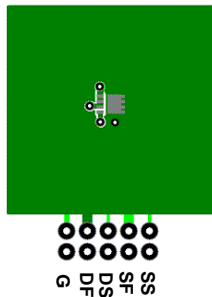
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 75\text{ V}, I_D = 4.6\text{ A}, V_{GS} = 10\text{ V}, R_{GEN} = 6\text{ }\Omega$		8.2	17	ns	
t_r	Rise Time			1.7	10	ns	
$t_{d(off)}$	Turn-Off Delay Time			14	26	ns	
t_f	Fall Time			3.1	10	ns	
$Q_{g(TOT)}$	Total Gate Charge		$V_{GS} = 0\text{ V to }10\text{ V}$		11	15	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0\text{ V to }5\text{ V}$	$V_{DD} = 75\text{ V}, I_D = 4.6\text{ A}$		6	9	nC
Q_{gs}	Total Gate Charge				2.8		nC
Q_{gd}	Gate to Drain "Miller" Charge				2.3		nC

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = 4.6\text{ A}$ (Note 2)		0.79	1.3	V
		$V_{GS} = 0\text{ V}, I_S = 2\text{ A}$ (Note 2)		0.75	1.2	
t_{rr}	Reverse Recovery Time	$I_F = 4.6\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$		58	93	ns
Q_{rr}	Reverse Recovery Charge			63	102	nC

NOTES:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



53 °C/W when mounted on a 1 in² pad of 2 oz copper



125 °C/W when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.

3. Starting $T_J = 25\text{ }^\circ\text{C}$; N-ch: L = 3 mH, $I_{AS} = 4.8\text{ A}$, $V_{DD} = 150\text{ V}$, $V_{GS} = 10\text{ V}$.

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

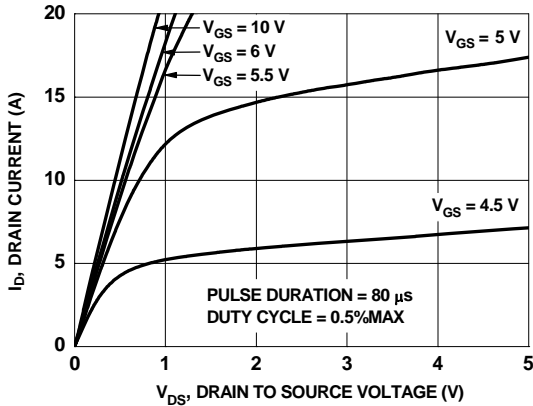


Figure 1. On-Region Characteristics

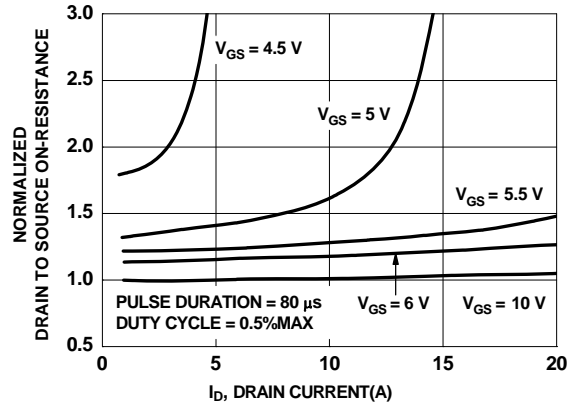


Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage

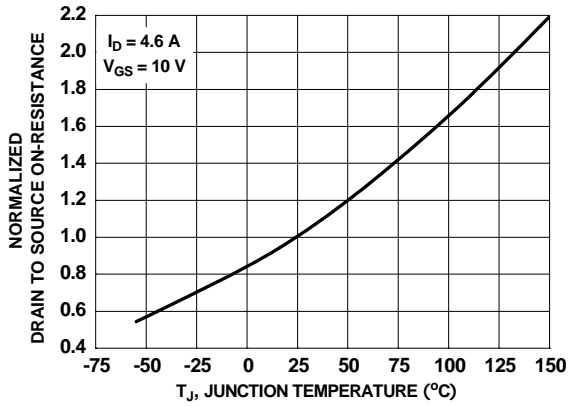


Figure 3. Normalized On-Resistance vs. Junction Temperature

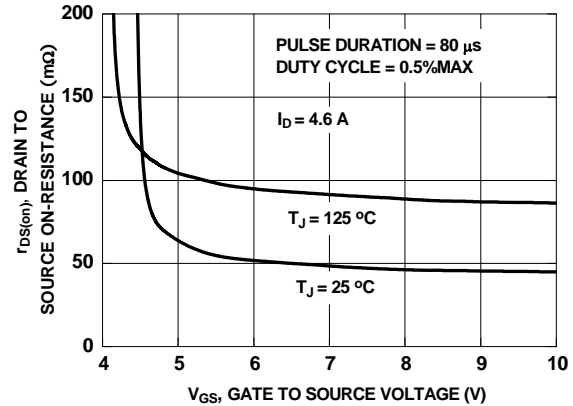


Figure 4. On-Resistance vs. Gate to Source Voltage

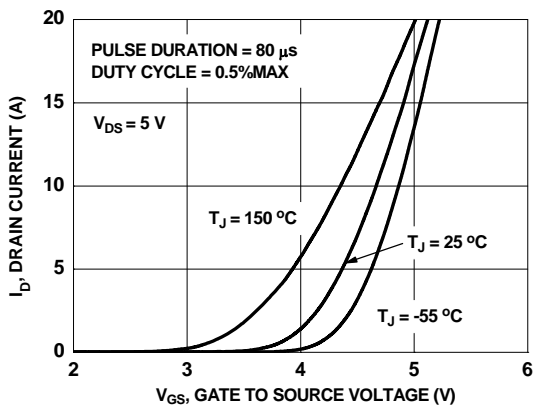


Figure 5. Transfer Characteristics

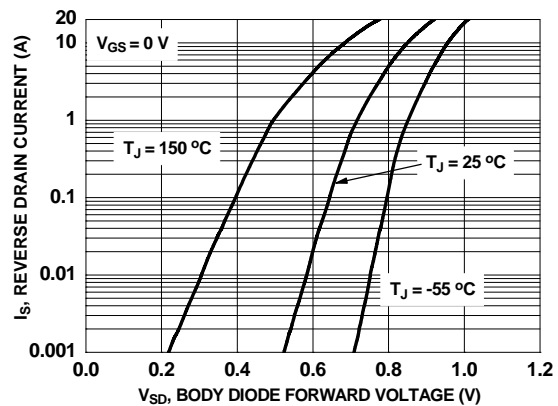


Figure 6. Source to Drain Diode Forward Voltage vs. Source Current

Typical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

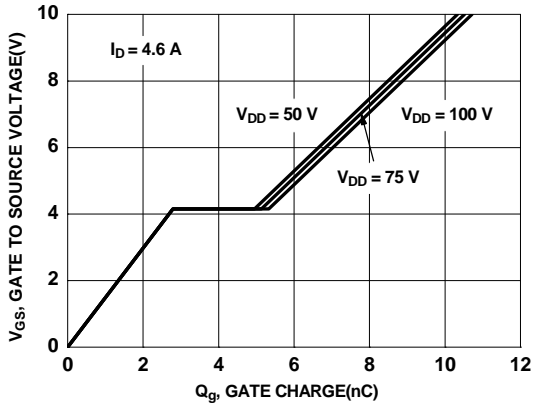


Figure 7. Gate Charge Characteristics

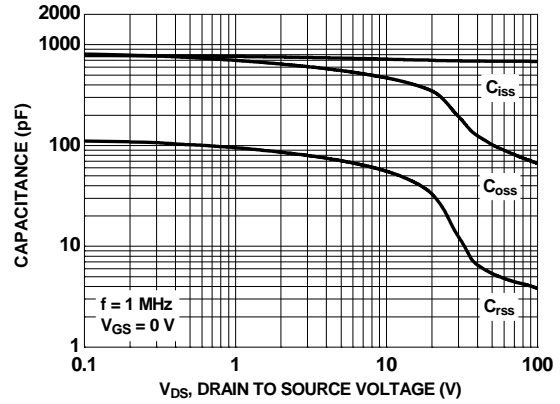


Figure 8. Capacitance vs. Drain to Source Voltage

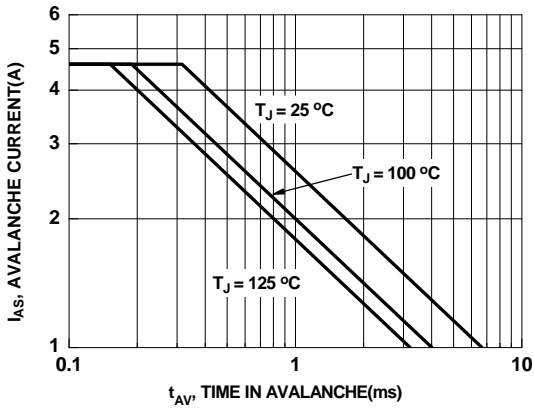


Figure 9. Unclamped Inductive Switching Capability

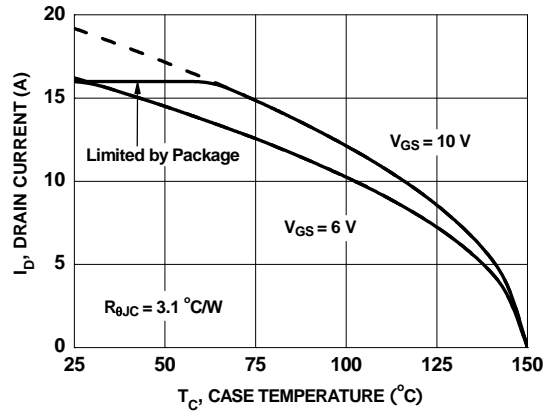


Figure 10. Maximum Continuous Drain Current vs. Case Temperature

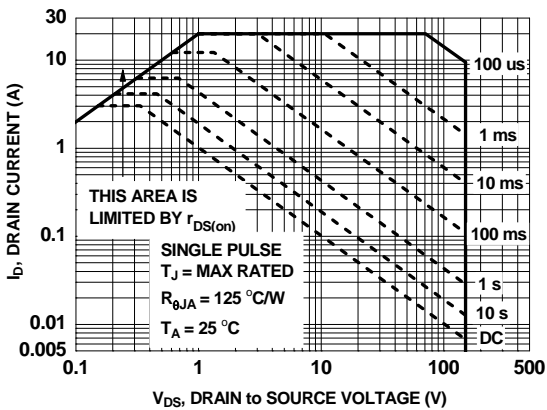


Figure 11. Forward Bias Safe Operating Area

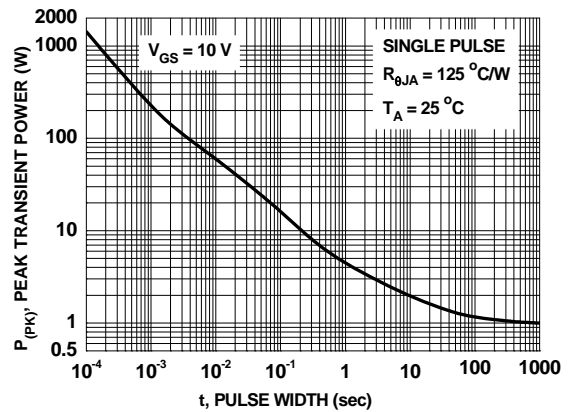


Figure 12. Single Pulse Maximum Power Dissipation

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

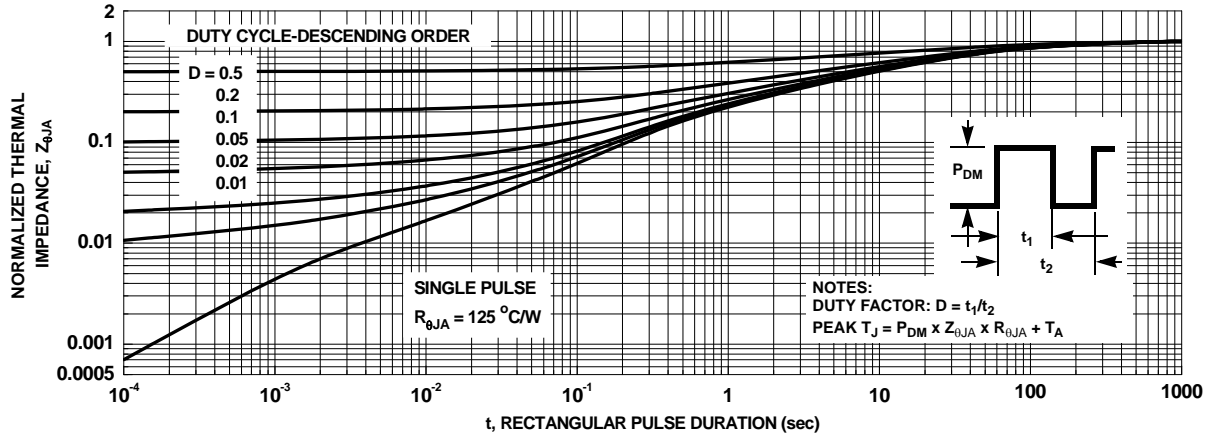
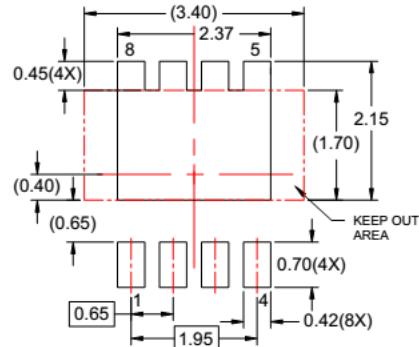
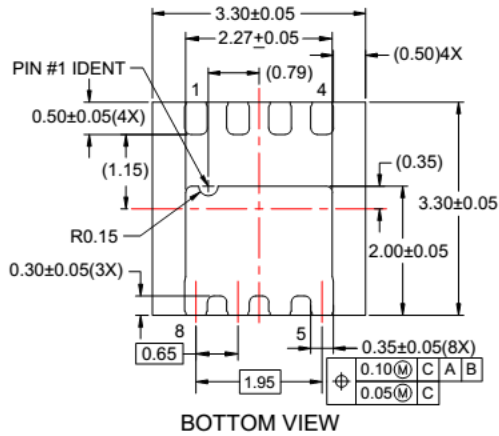
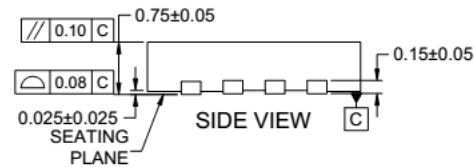
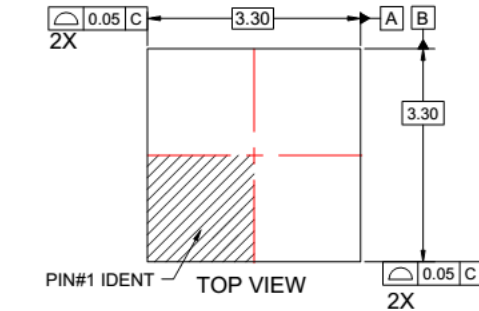


Figure 13. Transient Thermal Response Curve

Dimensional Outline and Pad Layout



NOTES:

- A. DOES NOT CONFORM TO JEDEC REGISTRATION MO-229
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
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